| 1 | Original Research Article |
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| 2 | Effective atomic numbers for some alloys at 662 keV |
| 3 | Using gamma rays backscattering technique |
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| 5 | ABSTRACT |
| 6 | The gamma backscattering is a useful technique in determining effective atomic number of |
| 7 | backscattering material. In gamma backscattering technique there is no direct contact with the |
| 8 | detector and material under study. So, in the present work the intensity distribution of |
| 9 | backscattered photons was determined both as a function of atomic number of the target and |
| 10 | thickness of the target and then find out the effective atomic number of (Pb-Sn, Pb-Zn and Zn- |
| 11 | Sn) alloys at 662 keV. These alloys were synthesized in different compositions of Pb, Sn and Zn |
| 12 | elements using melt quenching technique with the help of muffle furnace. The intensity |
| 13 | distribution of backscattered photons was recorded with the help of GAMMARAD5 (76 mm x |
| 14 | 76 mm NaI(Tl) scintillator detector. The experimental results so obtained were compared with |
| 15 | the theoretical ones which were computed using atomic to electronic cross-section method with |
| 16 | the help of mass attenuation coefficients database of WinXCom. A good agreement has been |
| 17 | observed between theoretical and experimental results of the effective atomic numbers for the |
| 18 | selected alloys. |
| 19 | Keywords: Backscattering, Effective Atomic Number, Binary Alloys. |
| 20 | 1. INTRODUCTION |
| 21 | The backscattering of photons plays important role in radiation shielding. It gives information |
| 22 | about the characteristics of the materials i.e. electron density, cross sections and effective atomic |
| 23 | number of the alloys. The numbers of backscattered photons increases with increase in target |
| 24 | thickness (Udagani, 2013). In backscattering technique the sample can be accessed from the |
| 25 | same side, imaging is simple and also the depth information of the sample is possible (Majid and |
| 26 | Balamesh, 2005). In the gamma backscattering, the intensity of backscatter gamma photons |
| 27 | depends on thickness of the material and the atomic number of the material. The "effective |
| 28 | atomic number" introduced by Hine (1952) has a physical meaning and is quite useful parameter |
| 29 | for interpretation of attenuation of X-ray or gamma radiation by a composite material. This |

30 number is also very useful to visualize a number of characteristics of a material of scientific and

- 31 biological interest (Singh et al., 2010). The gamma backscattering is strongly dependent on mass
- 32 numbers of the target atoms and effective atomic number (Z_{eff}) of the selected materials. Hence,
- 33 it is a useful technique in determining effective atomic number (Z_{eff}) of backscattering materials
- 34 (Sabharwal et al., 2009). In the present measurements effective atomic number of PbSn, PbZn
- 35 and ZnSn alloys was calculated by gamma backscattering. An element is mixed with another
- 36 element of different concentration to enhance mechanical properties such as tensile strength,
- 37 hardness mould ability etc. In the field of radiation physics, tin and zinc is added to lead to make
- 38 the alloy machine able and of high density so that it can be used as a good shielding material for
- 39 gamma rays. In the present work, PbSn, PbZn and ZnSn alloys are taken as these materials are
- 40 easily available and easy to prepare their alloys in the laboratory as the melting point of lead,
- 41 zinc and tin is low.

42 2. EXPERIMENTAL DETAILS

43 The binary alloys of Zn (Z=30), Sn (Z=50) and Pb (Z=82) were synthesized using melt quench 44 technique in different compositions using muffle furnace. The Zn (melting point: 419.527°C as 45 quoted at www.rsc.org/periodic-table/element/30/zinc), Sn (melting point: 231.928°C as quoted 46 at www.rsc.org/periodic-table/element/50/tin) and Pb (melting point: 327.462°C as quoted at 47 www.rsc.org/periodic-table/element/82/lead) metalloids granules (purity > 99.5%) procured from Nice chemicals (P) Ltd, India, were weighed in required amounts using electronic digital balance 48 49 (least count: 1 mg and maximum capacity: 500 g) and then heated in alumina crucible at 450 °C 50 for 10 minutes in muffle furnace and then poured quickly in cast iron mould of dimensions 2 x 2 $x \ 2 \ cm^3$ at room temperature. The chemical composition and physical properties of the prepared 51 samples were listed in the Table 1 and 2. The experimental work carried out using ¹³⁷Cs 52 53 radioactive isotopes by placing a gamma rays detector at an angle of 180° to the incident beam. 54 The backscattered photons were recorded using GAMMARAD5 (scintillator detector) of 55 dimensions 76 mm x 76 mm having energy resolution of 7% at 662 keV coupled with multichannel analyser (MCA) based on Amptek's DP5G Digital Pulse Processor for 600 s. The 56 scintillator detector has been placed in front of ¹³⁷Cs gamma rays source at a distance of 9.5 cm. 57

58 In order to calibrate the detector in terms of backscattering of gamma rays, different spectra were

recorded using calibration sources ⁵⁷Co (122 keV), ¹³³Ba (81 keV, 302 keV and 356 keV), ¹³⁷Cs 59 (662 keV), ²²Na (511 keV), ⁶⁰Co (1173 keV and 1332 keV) placed at the target position. After 60 calibration of the detector a particular incident energy photon ¹³⁷Cs (662 keV) irradiate on the 61 metals (13Al, 28Ni, 50Sn period and 82Pb) of varying thickness and all the spectra were recorded 62 63 with increasing thickness of selected metals ($_{13}$ Al, $_{28}$ Ni, $_{50}$ Sn period and $_{82}$ Pb) by placing them 64 behind the sources for the time of 600 s, so as to have sufficient number of counts (more than 65 10,000) under the area of backscattered peak (which appears at 200.91 keV). The metals (Al, Ni, Sn and Pb) of varying thickness are used as a target placed behind the sources at a distance of 9.5 66 67 cm from gamma rays detector. The recorded spectra were analyzed to measure the area under the backscattered photon. The contribution of backscattered photons was obtained after 68 69 subtracting area under the backscattered photon (with sample) from area under the backscattered 70 photon (without sample). The schematic of experimental set up is shown in the Fig. 1.

71 **3. RESULTS AND DISCUSSION**

72 The numbers of backscattered photons depend upon the atomic number of the target and 73 thickness of the target used in the experiment. So, in present work the intensity distribution of 74 backscattered photons was determined both as a function of atomic number of the target and thickness of the target. To use samples of different thickness the backscattered photons at 75 scattering angle 180° a typical backscattered peak (with sample) and a backscattered peak 76 77 (without sample) from the nickel target (thickness 19.0 mm) exposed to 662 keV gamma photons 78 is given in Fig. 2. We obtain the contribution of backscattered photons after subtracting this 79 observed backscattered peak (with sample) from backscattered peak (without sample). For 80 analysis of recorded spectrum, it is necessary to select the area under the peak. From the 81 recorded spectrum the backscattering peak area has been identified for experimental work. For 82 fixed experimental geometry the backscatter peak appears at around 200.91 keV when using the ¹³⁷Cs radioactive source. With the same experimental geometry the known metals (Al, Ni, Sn 83 and Pb) are placed at 180° with the ¹³⁷Cs radioactive source and detector assembly. The area 84 85 under the peak was recorded. The backscattering sample thickness was increased by placing 86 known metals (Al, Ni, Sn and Pb) one by one behind the previously placed known metals 87 without disturbing the experimental geometry. This procedure is repeated for targets of different

88 metals and different thicknesses to evaluate the intensity of multiply backscattered photons, when exposed to 662 keV gamma photons from ¹³⁷Cs source. The number of backscattered 89 90 counts, for different metals (Al, Ni, Sn and Pb) as a function of target thickness is shown in Fig.2 91 .The numbers of backscattered counts increases with increase in target thickness. A calibration 92 line is drawn between the backscattered counts and the value of atomic number of elemental 93 targets (Al, Ni, Sn and Pb). The solid curves represent the best-fit curves through the experimental data points corresponding to backscattered counts. At 180° scattering angle, the 94 95 best fitted line is shown in Fig. 3. The numbers of backscattered counts increases due to the fact 96 that an increase in target thickness results in higher number of scattering centres for the 97 interaction of primary gamma rays with target material. The backscattering of gamma photons, is 98 successfully used as an experimental technique for the evaluation of "effective atomic number" 99 of alloys of known composition. The "effective atomic number" of an alloy Z_{eff}, provides 100 conclusive information about the alloy when gamma radiations are incident on it. The number of 101 backscattered counts for 662 keV gamma photons in alloys provide the "effective atomic 102 number" of these alloys using best-fit curves (Figs. 4 - 6) through the experimental data points 103 for pure elements (Al, Ni, Sn and Pb) at scattering angles of 180°. Now each of the target of 104 which the effective atomic number is to be determined is replaced by the elemental target and 105 again the scattered spectra are recorded for the same duration of time at scattering angles of 180° . 106 The backscattered counts mentioned in Table 3 are marked on the calibration line in Fig. 4, 5 and 6 corresponding to the scattering angles 180° and the corresponding atomic number values are 107 108 interpolated along the X-axis. These values are the effective atomic number of alloys under 109 study. The effective atomic numbers of these samples are also evaluated from known elemental 110 concentration of the constituent elements using ratio of atomic to electronic cross-section method 111 (Singh T. et al. 2007; Sharma R. et al. 2012). The theoretical Z_{eff} values were obtained using 112 mass attenuation coefficient database of WinXCom (Gerward et al.; 2001) agreed with the 113 experimental measured values. The number of backscattered counts for the selected alloy of 114 different target thickness as a function of atomic number is shown in Figs. 4 - 6. It have been 115 observed that the number of backscattered counts decreases with the increase in atomic numbers 116 due to increase in number of scattering centres for the interaction of primary gamma rays with 117 target metals. It has also been observed that the numbers of multiply backscattered counts 118 increases with decrease in atomic numbers. The measured values of multiply backscattered 119 counts using 662 keV gamma photons from targets of selected alloys are given in columns 2 of 120 Table 3. The third and fourth column in the table provides theoretical and experimental values of 121 effective atomic numbers for different composition of alloys. There is a need of experiment and 122 theoretical data for gamma backscattering for alloys of industrial and nuclear interest as there is 123 no experimental data and theoretical data tables available in literature for these materials. 124 Knowledge of gamma backscattering is useful in the calculation of effective atomic number, 125 absorption and also in the field of radiation dosimetry and reactor shielding. The slight deviation 126 of experimental results from the theoretical data may be due to the non-uniformity of target's 127 thickness.

128 **4. CONCLUSION**

Gamma rays backscattering technique provides non-destructive method for successfully assigning effective atomic numbers to the selected alloys. This method has an additional benefit over other experimental techniques: Rayleigh to Compton scattering ratio (Singh M.P. et al. 2010), multiple scattering at different angles (Singh G. et al., 2010) that it works at lower source strength, hence reducing the cost factor in terms of less shielding requirements for the experimental setup. Moreover, it requires less time duration as compared to other experimental techniques.

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139 **REFERENCES**

- Hine G.J. (1952) The effective atomic numbers of materials for various gamma ray
 interactions, *Phys. Rev.*, 85: 725.
- Gerward L., Guilbert N., Jensen K.B., Levring H. (2001) X-ray absorption in matter.
 Reengineering XCOM. *Radiat. Phys. Chem.* 60: 23.

- Majid S.A., Balamesh A. (2005) Imaging corrosion under insulation by gamma ray
 backscattering Method. *Middle East Non-destructive Testing Conference & Exhibition pp*27-30 Nov. 2005, Bahrain, Manama.
- Singh T., Kaur P., Singh P.S. (2007) A study of photon interaction parameters in some
 commonly used solvents. *J. Radiol. Prot.* 27: 79.
- Sabharwal A.D., Singh B., Sandhu B.S. (2009) Investigations of multiple backscattering
 and albedos of 1.12 MeV gamma rays in aluminium. *Nucl. Inst. Meth* B 267: 151.
- 6. Singh M.P., Sharma A., Singh B., Sandhu B.S., (2010) Non-destructive evaluation of
 scientific and biological samples by scattering of 145 keV gamma rays. *Radiat*. *Measurements*, 45: 960.
- 154 7. Singh G., Singh M., Singh B., Sandhu B.S., (2010) Experimental observation of Z155 dependence of saturation depth of 0.662 MeV multiply scattered gamma rays. *Nucl.*156 *Instru. Methods B*, 251: 73.
- 157 8. Sharma R., Sharma V., Singh P.S., Singh T. (2012) Effective atomic numbers for some
 158 Calcium-strontium-borate glasses. *Ann. Nucl. Energy* 45: 144.
- Udagani C. (2013). Study of Gamma Backscattering and Saturation Thickness Estimation
 for Granite and Glass. *Int. J. Eng. Sci. Invention.* 2: 86.
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Table 1 Chemical composition of prepared alloy samples

| Sample No. | | Selected alloys | Chemical Composition (Fractional weight) | |
|------------|-------------|-----------------|---|--|
| 1. | Pb-Sn | Pb80Sn20 | Pb=0.80, Sn=0.20 | |
| | | Pb60Sn40 | Pb=0.60, Sn=0.40 | |
| | | Pb40Sn60 | Pb=0.40, Sn=0.60 | |
| | | Pb20Sn80 | Pb=0.20, Sn=0.80 | |
| 2. | Pb-Zn Pb80Z | | Pb=0.80, Zn=0.20 | |
| | | Pb50Zn50 | Pb=050, Zn=0.50 | |
| | | Pb40Zn60 | Pb=0.40, Zn=0.60 | |
| 3. | Zn-Sn | Zn80Sn20 | Zn=0.80, Sn=0.20 | |
| | | Zn60Sn40 | Zn=0.60, Sn=0.40 | |
| | | Zn70Sn30 | Zn=0.70, Sn=0.30 | |

Table 2 Properties of the prepared alloy samples

| Sample No. | Selected alloys | | Thickness | Volume | Mass | Density |
|------------|-----------------|----------|-----------|----------------------------|------------|------------|
| | | | (cm) | (cm ³) | (g) | (g/cm^3) |
| 1. | PbSn | Pb80Sn20 | 0.750 | 2.94 | 27.19 | 9.25 |
| | | Pb60Sn40 | 0.820 | 3.46 | 27.87 | 8.07 |
| | | Pb40Sn60 | 0.877 | 3.22 | 27.07 | 8.41 |
| | | Pb20Sn80 | 0.870 | 3.50 | 24.76 | 7.08 |
| 2. | PbZn | Pb80Zn20 | 0.540 | 2.66 | 19.92 | 9.62 |
| | | Pb50Zn50 | 0.400 | 1.55 | 11.44 | 7.36 |
| | | Pb40Zn60 | 0.600 | 2.24 | 12.00 | 5.33 |
| 3. | ZnSn | Zn80Sn20 | 0.630 | 2.07 | 16.8 | 6.67 |
| | | Zn60Sn40 | 0.530 | 1.55 | 14.33 | 6.57 |
| | | Zn70Sn30 | 0.600 | 2.25 | 12.41 | 6.85 |

| Sample No. | Selected Alloys | | No. of backscattered counts | Z _{eff} (Theoretical) | Z _{eff} (Experimental) |
|---------------|-----------------|----------|-----------------------------------|-----------------------------------|------------------------------------|
| 1. | Pb-Sn | Pb80Sn20 | 7258 | 75.7 | 76.64 |
| | | Pb60Sn40 | 9436 | 69.3 | 70.35 |
| | | Pb40Sn60 | 10374 | 63.7 | 63.9 |
| | | Pb20Sn80 | 10835 | 56.5 | 56.9 |
| 2. | Pb-Zn | Pb80Zn20 | 9071 | 72.2 | 71.8 |
| | | Pb50Zn50 | 10354 | 57.1 | 58.07 |
| | | Pb40Zn60 | 10208 | 49.9 | 52.5 |
| 3. | Zn-Sn | Zn80Sn20 | 15628 | 34.3 | 35.9 |
| | | Zn60Sn40 | 13356 | 38.4 | 40.65 |
| | | Zn70Sn30 | 13486 | 37.0 | 39.5 |

Table 3 Effective Atomic Numbers for selected alloys at 662 keV gamma photons.







Figure 3: Number of backscattered counts for selected metals (13Al, 28Ni, 50Sn and 82Pb) as

a function of target thickness



Figure 4 : Variation of backscattered counts with atomic number for Pb-Zn alloys of
 different compositions at 662 keV gamma photons







210 Figure 5: Variation of backscattered counts with atomic number for Zn-Sn alloys of

different compositions at 662 keV gamma photons



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213 Figure 6: Variation of back Scatter counts with atomic number for Pb-Sn alloys of

different compositions at 662 keV gamma photons